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30V N-Channel MOSFET

SOT-23

Pin Definition:



- 1. Gate
- 2. Source
- 3. Drain

PRODUCT SUMMARY

V _{DS} (V)	$R_{DS(on)}(m\Omega)$	I _D (A)	
30	30 @ V _{GS} = 10V	5.8	
	43 @ V _{GS} = 4.5V	5.0	

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

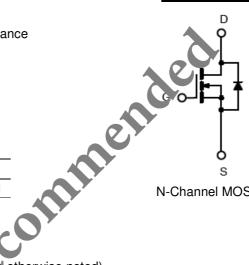
- Load Switch
- PA Switch

Ordering Information

Part No.	Package	Packing
TSM3404CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denotes Halogen Free Product.

Block Diagram



N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C un is otherwise noted)

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current		I _D	5.8	Α	
Pulsed Drain Current		I _{DM}	20	Α	
Continuous Source Current (Diode Co	nduction) ^{a,b}	I _S	2.5	Α	
Maximum Power Dissipation	Ta = 25°C		0.75	W	
	Ta = 75°C	P _D	0.48		
Operating Junction Temperature		T _J	+150	°C	
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit	
Junction to Foot Thermal Resistance	R⊖ _{JF}	75	°C/W	
Junction to Ambient Thermal Resistance (PCB mounted)	RO _{JA}	140	°C/W	

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, $t \le 10$ sec.



30V N-Channel MOSFET

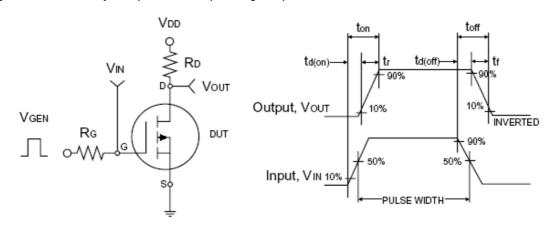


Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	V _{GS(TH)}	1	1.4	3	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	μΑ
Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$	I _{DSS}			1.0	μΑ
On-State Drain Current	$V_{DS} = 5V, V_{GS} = 4.5V$	I _{D(ON)}	20			Α
Drain Course On State Besistance	$V_{GS} = 10V, I_D = 5.8A$	Ь		23	30	
Drain-Source On-State Resistance	rain-Source On-State Resistance $V_{GS} = 4.5V$, $I_D = 5A$		35	43	mΩ	
Forward Transconductance	$V_{DS} = 5V, I_{D} = 5A$	g _{fs}		25	-	S
Diode Forward Voltage	$I_S = 1.0A, V_{GS} = 0V$	V _{SD}		0.76	1	V
Dynamic ^b						
Total Gate Charge	$V_{DS} = 15V, I_D = 5.8A,$	O _a		4.52		
Gate-Source Charge	$V_{DS} = 15V, I_D = 5.6A,$ $V_{GS} = 10V$			1.24		nC
Gate-Drain Charge	V _{GS} = 10 V	Q_{gd}		1.68		
Input Capacitance	\ 15\\ \\ 0\\	C _{iss}		400.96		
Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V$ f = 1.0MHz	C _{oss}		100.47		pF
Reverse Transfer Capacitance	T = T.UIVINZ	C_{rss}		71.82		
Switching ^c						
Turn-On Delay Time	V 251	t _{d(on)}		7.42		
Turn-On Rise Time	$V_{DF} = 5V$, $\tau_{L} = 2.2\Omega$,	t _r		3.41		20
Turn-Off Delay Time	$I_D = 1$, $V_{GEN} = 10V$,	t _{d(off)}		20.4		nS
Turn-Off Fall Time	$rac{1}{2}_{G} = 6\Omega$	t _f		3.01		

Notes:

- a. pulse test: PW $\leq 300 \mu S$, define the $\leq 2\%$ b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

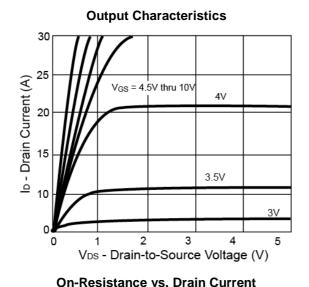
Switchin Waveforms

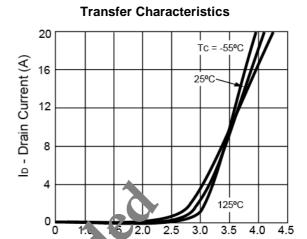


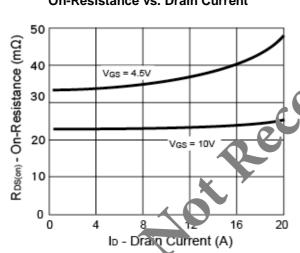
30V N-Channel MOSFET

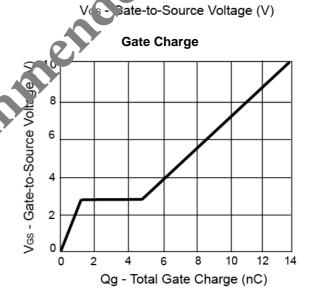


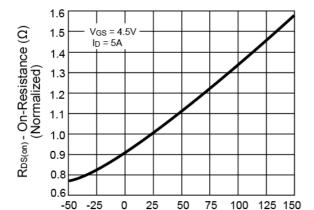
Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)





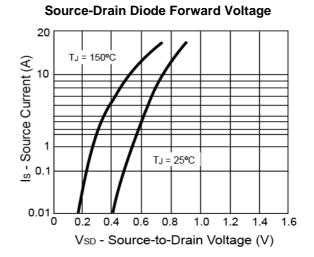






Tj - Junction Temperature (°C)

On-Resistance vs. Junction Temperature

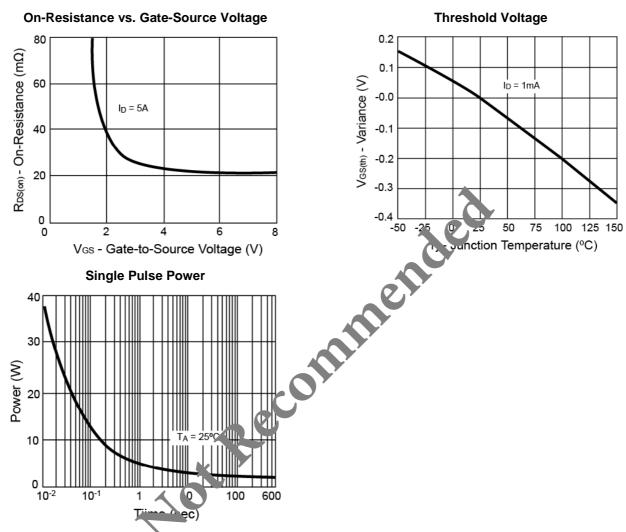




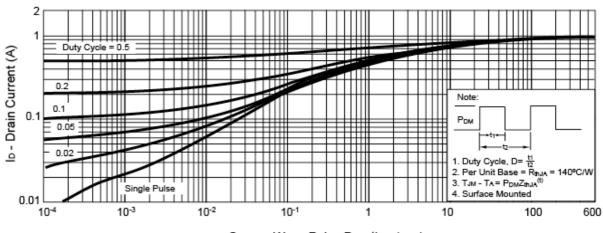
30V N-Channel MOSFET



Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



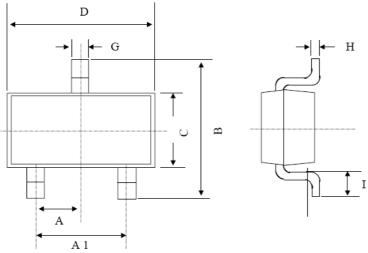
Square Wave Pulse Duration (sec)



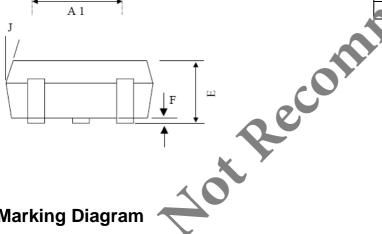
30V N-Channel MOSFET



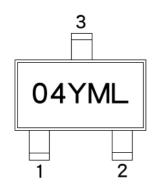
SOT-23 Mechanical Drawing



SOT-23 DIMENSION					
DIM	MILLIMETERS		INCHES		
ווועו	MIN	MAX	MIN	MAX.	
Α	0.95	BSC	0.037	7 BSC	
A1	1.9 BSC 0.074 BSC		BSC		
В	2.60	3.00	0.102	0.118	
С	1.40	1.70	0.055	0.067	
D	2.80	`10	0.110	0.122	
Е	1.00	1.30	0.039	0.051	
F	0.0	0.10	0.000	0.004	
G	0.55	0.50	0.014	0.020	
Н	0.10	0.20	0.004	0.008	
	0.30	0.60	0.012	0.024	
	5º	10⁰	5º	10⁰	



Marking Diagram



04 = Device Code

Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep X =Oct Y =Nov **Z** =Dec

L = Lot Code



TSM3404 30V N-Channel MOSFET



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